NPN Epitaxial Planar Transistor

BTD2195J3

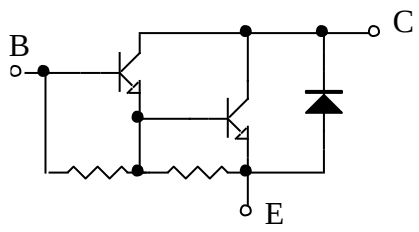
BV_{CEO}	120V
I_C	4A
R_{CESAT}	600mΩ

Description

The BTD2195J3 is a NPN Darlington transistor, designed for use in general purpose amplifier and low speed switching application. RoHS compliant package process is adopted.

Equivalent Circuit

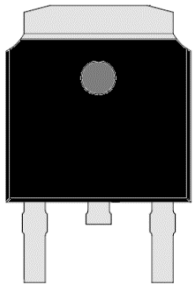
BTD2195J3



B：Base
C：Collector
E：Emitter

Outline

TO-252



B C E

Absolute Maximum Ratings (Ta=25°C)

Parameter	Symbol	Limits	Unit
Collector-Base Voltage	V_{CBO}	130	V
Collector-Emitter Voltage	V_{CEO}	120	V
Emitter-Base Voltage	V_{EBO}	5	V
Collector Current (DC)	I_C	4	A
Collector Current (Pulse)	I_{CP}	6 (Note)	A
Power Dissipation	Pd(T_A=25℃)	1.5	W
	Pd(T_C=25℃)	20	W
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	83.3	°C/W
Thermal Resistance, Junction to Case	$R_{\theta JC}$	6.25	°C/W
Junction Temperature	Tj	150	°C
Storage Temperature	Tstg	-55~+150	°C

Note : Single Pulse Pw≦350μs, Duty≦2%.

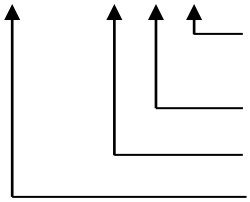
Characteristics (Ta=25°C)

Symbol	Min.	Typ.	Max.	Unit	Test Conditions
BV_{CEO}	120	-	-	V	I_C=1mA, I_B=0
BV_{CBO}	130	-	-	V	I_C=100μA, I_E=0
I_{CBO}	-	-	1	mA	V_{CB}=100V, I_E=0
I_{CEO}	-	-	2	mA	V_{CE}=50V, I_E=0
I_{EBO}	-	-	2	mA	V_{EB}=5V, I_C=0
*$V_{CE(sat)}$	-	-	1.25	V	I_C=2A, I_B=8mA
*$V_{CE(sat)}$	-	-	1.5	V	I_C=2A, I_B=2mA
*$V_{BE(on)}$			2.2	V	V_{CE}=4V, I_C=2A
*$h_{FE}1$	600	-	-	-	V_{CE}=3V, I_C=1A
*$h_{FE}2$	1000	-	-	-	V_{CE}=3V, I_C=2A
*$h_{FE}3$	300	-	-	-	V_{CE}=3V, I_C=4A
Cob	-		200	pF	V_{CB}=10V, I_E=0A, f=1MHz

*Pulse Test : Pulse Width ≤380μs, Duty Cycle≤2%

Ordering Information

Device	Package	Shipping
BTD2195J3-0-T3-G	TO-252 (Pb-free lead plating and halogen-free package)	2500 pcs / Tape & Reel



Environment friendly grade : S for RoHS compliant products, G for RoHS compliant and green compound products

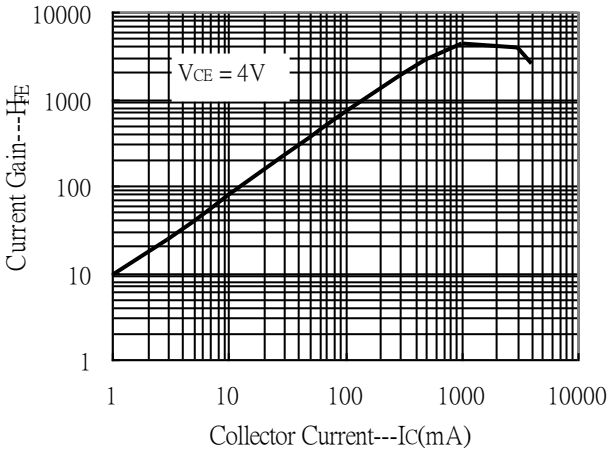
Packing spec, T3 : 2500 pcs / tape & reel,13” reel

Product rank, zero for no rank products

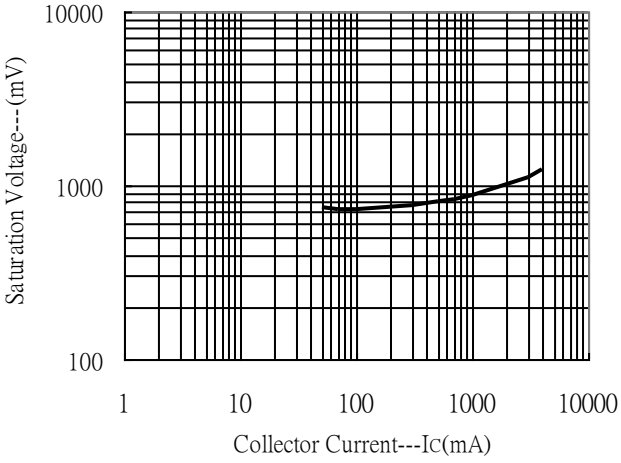
Product name

Typical Characteristics

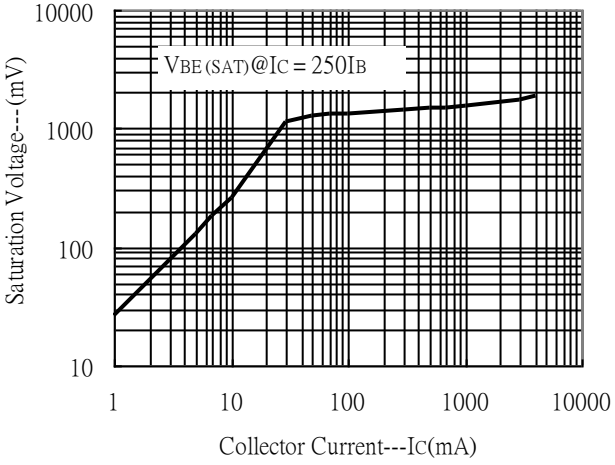
Current Gain vs Collector Current



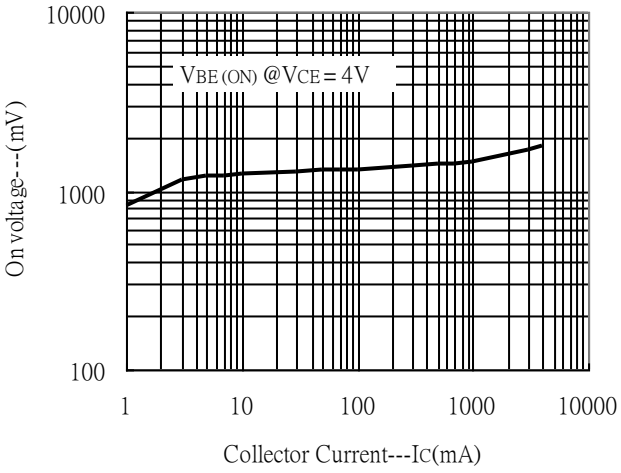
Saturation Voltage vs Collector Current



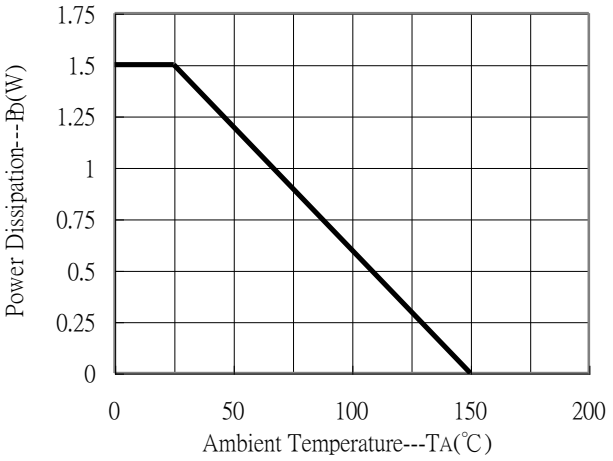
Saturation Voltage vs Collector Current



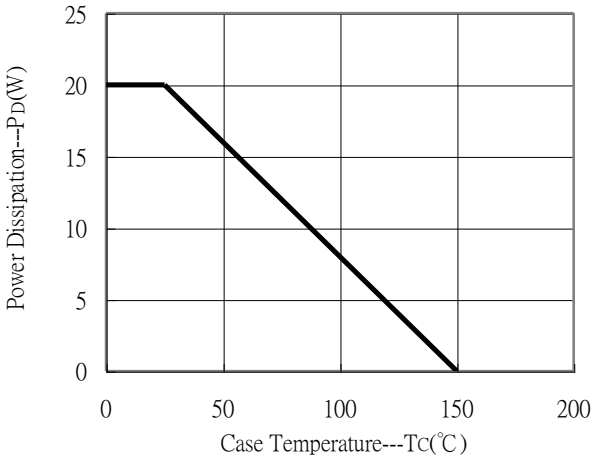
On voltage vs Collector Current



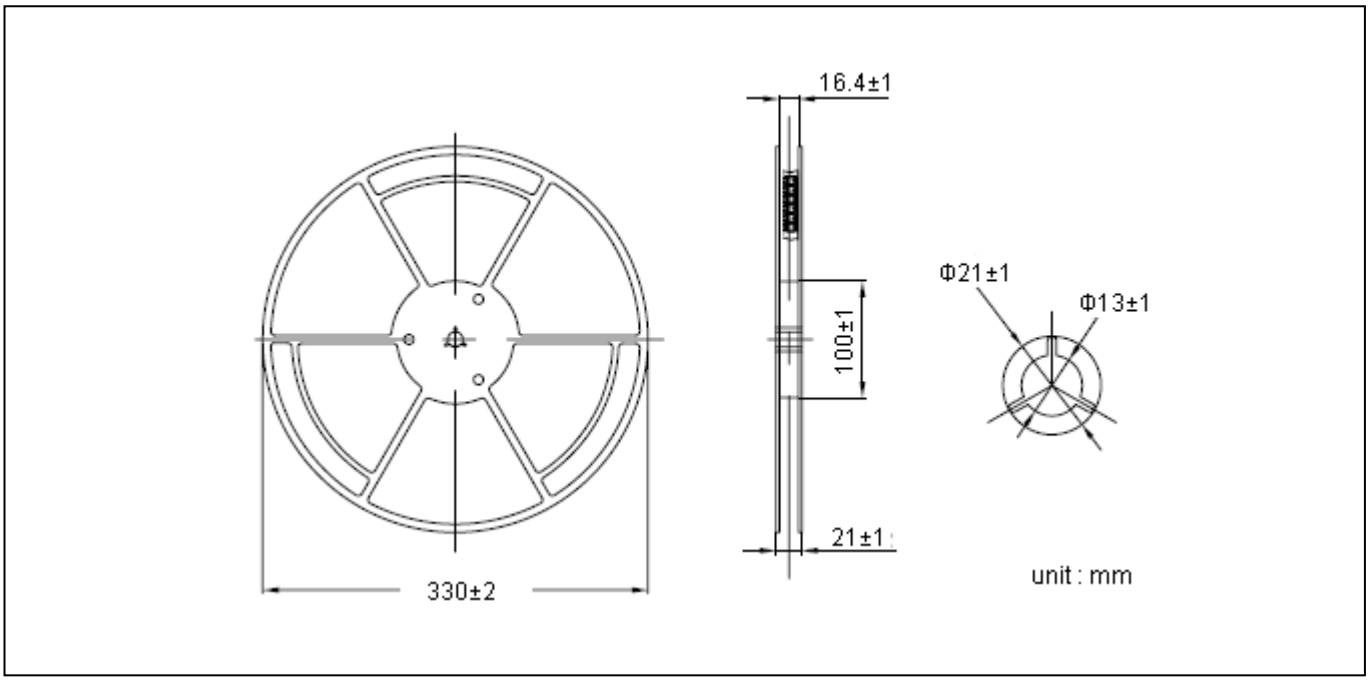
Power Derating Curve



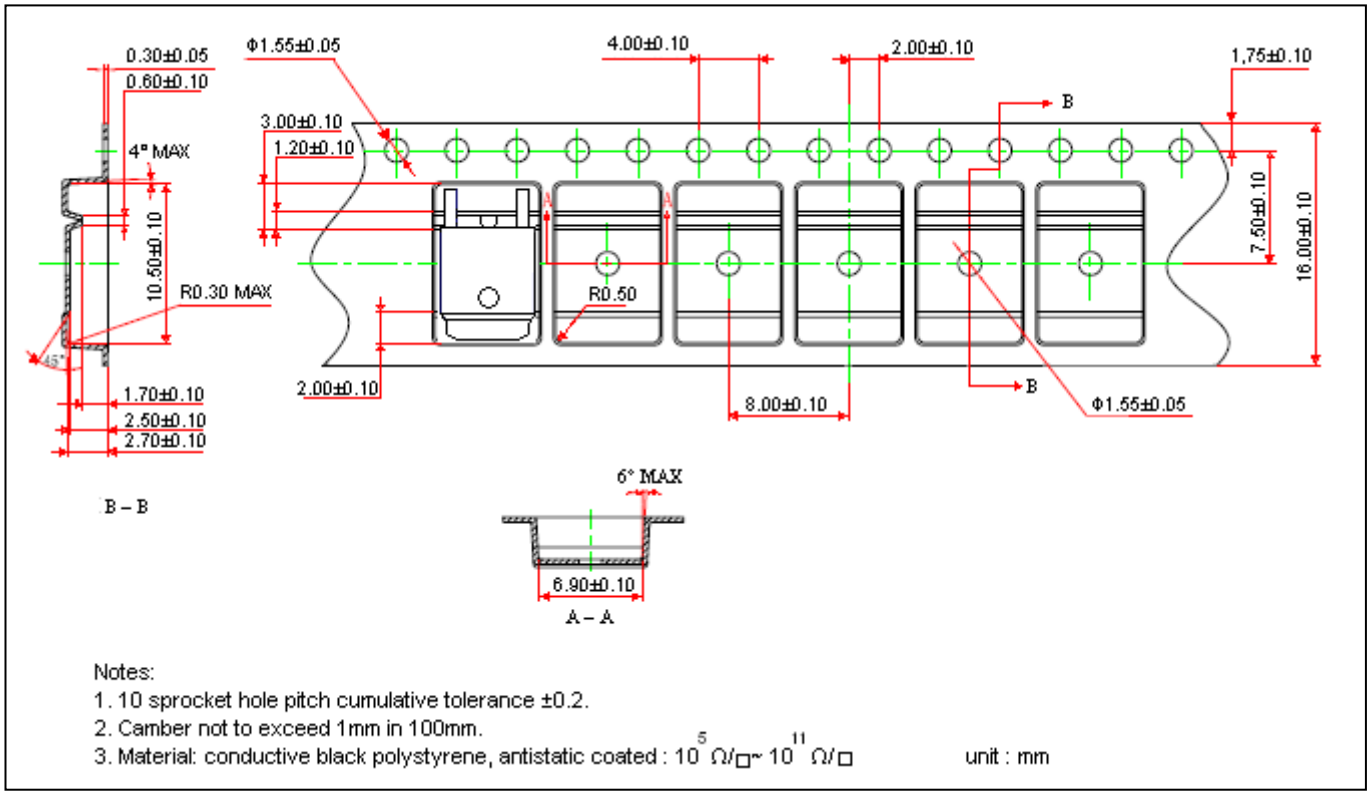
Power Derating Curve



Reel Dimension



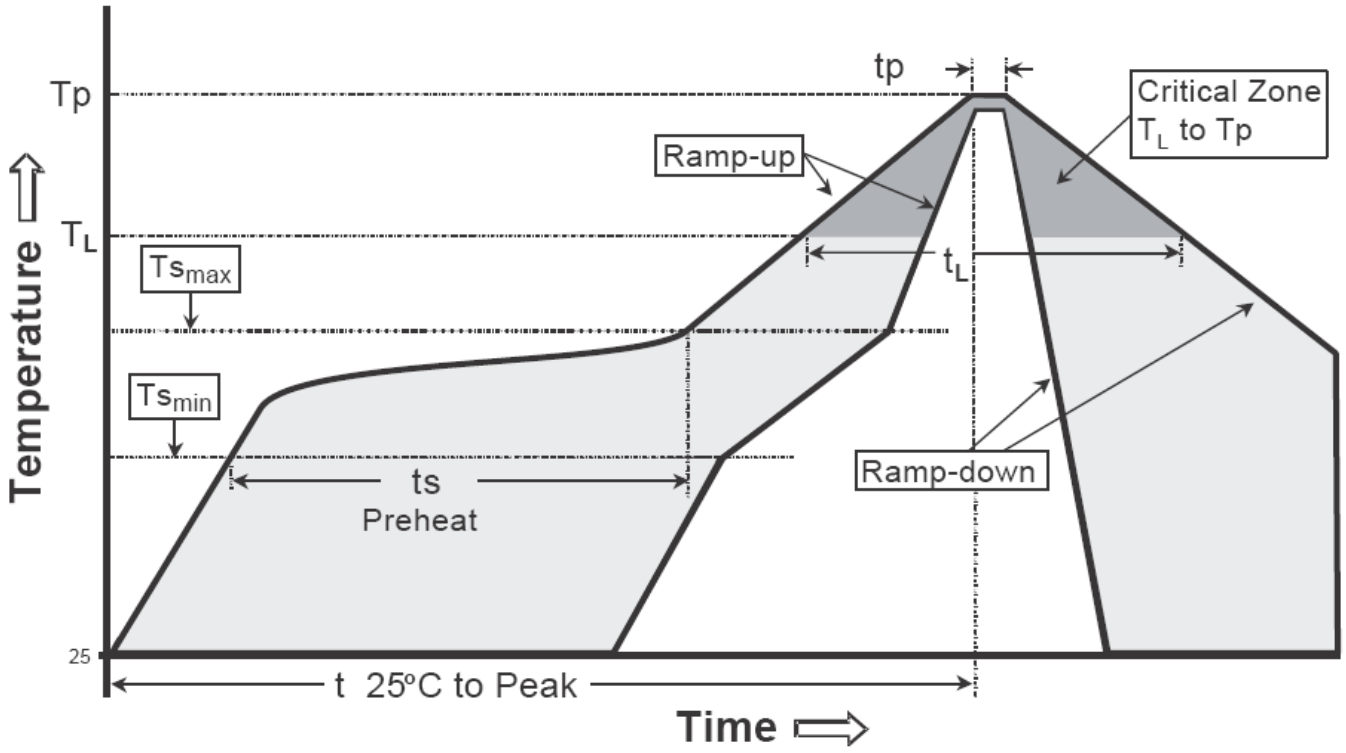
Carrier Tape Dimension



Recommended wave soldering condition

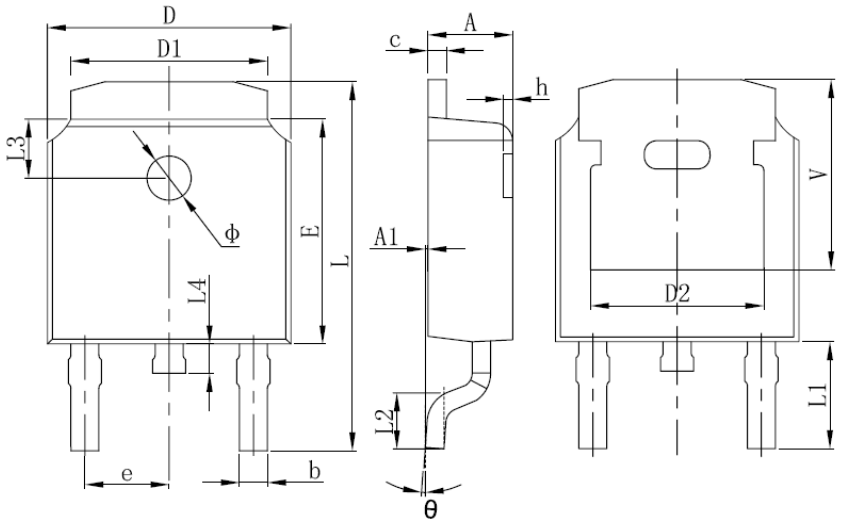
Product	Peak Temperature	Soldering Time
Pb-free devices	260 +0/-5 °C	5 +1/-1 seconds

Recommended temperature profile for IR reflow

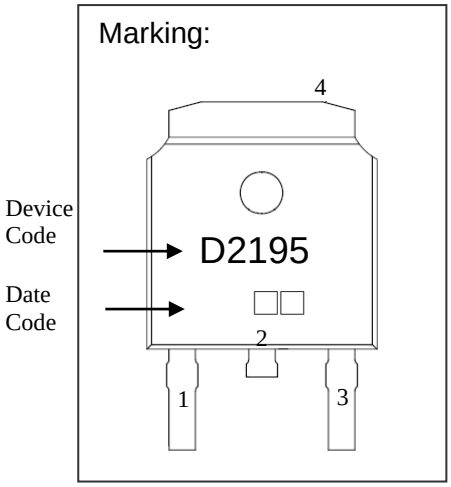


Profile feature	Sn-Pb eutectic Assembly	Pb-free Assembly
Average ramp-up rate (Tsmax to Tp)	3°C/second max.	3°C/second max.
Preheat −Temperature Min(T_S min) −Temperature Max(T_S max) −Time($t_{s\ min}$ to $t_{s\ max}$)	 100°C 150°C 60-120 seconds	 150°C 200°C 60-180 seconds
Time maintained above: −Temperature (T_L) − Time (t_L)	 183°C 60-150 seconds	 217°C 60-150 seconds
Peak Temperature(T_P)	240 +0/-5 °C	260 +0/-5 °C
Time within 5°C of actual peak temperature(tp)	10-30 seconds	20-40 seconds
Ramp down rate	6°C/second max.	6°C/second max.
Time 25 °C to peak temperature	6 minutes max.	8 minutes max.

TO-252 Dimension



3-Lead TO-252 Plastic Surface Mount Package
CYStek Package Code: J3



Style: Pin 1.Base 2.Collector 3.Emitter 4.Collector

Date Code :
First code : Year code, Last digit of Christian Year
Second Code : Month code, 1~9, A, B, C

DIM	Inches		Millimeters		DIM	Inches		Millimeters	
	Min.	Max.	Min.	Max.		Min.	Max.	Min.	Max.
A	0.087	0.094	2.200	2.400	L	0.382	0.406	9.712	10.312
A1	0.000	0.005	0.000	0.127	L1	0.114 REF		2.900 REF	
b	0.025	0.030	0.635	0.770	L2	0.055	0.067	1.400	1.700
c	0.018	0.023	0.460	0.580	L3	0.063 REF		1.600 REF	
D	0.256	0.264	6.500	6.700	L4	0.024	0.039	0.600	1.000
D1	0.201	0.215	5.100	5.460	Φ	0.043	0.051	1.100	1.300
D2	0.190 REF		4.830 REF		θ	0°	8°	0°	8°
E	0.236	0.244	6.000	6.200	h	0.000	0.012	0.000	0.300
e	0.086	0.094	2.186	2.386	V	0.207 REF		5.250 REF	

Notes: 1.Controlling dimension: millimeters.
2.Maximum lead thickness includes lead finish thickness, and minimum lead thickness is the minimum thickness of base material.
3.If there is any question with packing specification or packing method, please contact your local CYStek sales office.

Material:

- Lead : Pure tin plated.
- Mold Compound: Epoxy resin family, flammability solid burning class: UL94V-0.